RICOH

100 mA Ultra-low Supply Current (0.3 µA) LDO Regulator with Battery Monitor

No. EA-503-191025

OVERVIEW

The RP124x is an LDO regulator with a battery monitor (BM) featuring ultra-low supply current. The battery monitor has a function which divides the input voltage (V_{IN}) into 1/3 or 1/4. The battery charge remaining can be monitored by MCU. The buffering output enables directly inputting a signal into the low voltage A/D converter (ADC) with built-in MCU.

KEY BENEFITS

- Achieving Low Supply Current of 0.3 μA, Longer Battery Life and Downsizing
- Requiring Only Three External Capacitors and Suitable for Space-saving Mounting for the Smaller Packages

KEY SPECIFICATIONS

LDO Section

- Input Voltage Range: 1.7 V to 5.5 V
- Supply Current: Typ. 0.2 µA
- Output Voltage Accuracy: ±0.8%
- Output Current: 100 mA
- Ceramic Capacitor Compatible: 1.0 µF or more

BM Section

- Output Voltage: V_{IN}/3 (RP124xxx3x) V_{IN}/4 (RP124xxx4x)
- Supply Current: Typ. 0.1 µA
- Ceramic Capacitor Compatible: 0.1 µF to 0.22 µF





APPLICATIONS

- Battery powered IoT devices
- Energy harvesting devices
- Low power wireless communication modules including: Bluetooth® LE, Zigbee, and LPWA
- Low power consumption CPUs, memories, and sensors

PACKAGES





DFN1212-6 1.2 mm x 1.2 mm x 0.4 mm

SOT-23-5 2.9 mm x 2.8 mm x 1.1 mm

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SELECTION GUIDE

The LDO set output voltage, the divided ratio of BM output voltage, the CE pin function and the auto-discharge function are user-selectable options.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP124Lxx#*-TR	DFN1212-6	5,000 pcs	Yes	Yes
RP124Nxx#*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes

xx: Specify the LDO set output voltage (V_{SET}).

1.2 V (12) / 1.5 V (15) / 1.8 V (18) / 2.1 V (21) / 2.2 V (22) / 2.3 V (23) / 2.4 V (24) / 2.5 V (25) / 2.7 V (27) / 2.8 V (28) / 3.0 V (30) / 3.1 V (31) / 3.3 V (33) / 3.6 V (36) Contact Ricoh sales representatives for other voltages.

#: Specify the divided ratio of BM output voltage.

- 3: VIN/3
- 4: V_{IN}/4

*: Specify the CE pin and the auto-discharge option.

*	CE pin	Auto-discharge	
	Operate all and the OF air (Applies bight)	LDO	No
B Controlling LDO with the CE pin (Active-high		BM	No
	Operate all and the OF air (Applies bight)	LDO	Yes
D	Controlling LDO with the CE pin (Active-high)	BM	No
_		LDO	No
E	Controlling Bivi with the CE pin (Active-high)	BM	Yes

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BLOCK DIAGRAMS



RP124xxxxB Block Diagram



RP124xxxxD Block Diagram

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RP124xxxxE Block Diagram

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PIN DESCRIPTIONS





RP124L (DFN1212-6) Pin Configuration



RP124N (SOT-23-5) Pin Configuration

RP124L (DFN1212-6) Pin Description

Pin No.	Symbol	Description	
1	VOUT	Output Pin	
2	GND	Ground Pin	
3	BM	Battery Monitoring Output Pin	
4	CE	Chip Enable Pin, Active-high	
5	NC	No Connection	
6	VDD	Input Pin	

RP124N (SOT-23-5) Pin Description

Pin No.	Symbol	Description		
1	VDD	Input Pin		
2	GND	Ground Pin		
3	CE	Chip Enable Pin, Active-high		
4	BM	Battery Monitoring Output Pin		
5	VOUT	Output Pin		

⁽¹⁾ The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.



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ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

Symbol		Item	Rating	Unit
Vin	Input Voltage		-0.3 to 6.5	V
V _{CE}	CE Pin Voltage	9	-0.3 to 6.5	V
Vout	VOUT Pin Volt	age	-0.3 to V _{IN} + 0.3	V
V _{BM}	BM Pin Voltage	-0.3 to V _{IN} + 0.3	V	
I _{OUT}	Output Current	130	mA	
D-	Power	DFN1212-6 (JEDEC STD. 51-7 Test Land Pattern)	850	mW
PD	Dissipation ⁽¹⁾ SOT-23-5 (JEDEC STD. 51-7 Test Land Pattern)		660	mW
Tj	Junction Temp	-40 to 125	°C	
Tstg	Storage Temp	erature Range	-55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions

Symbol	Item Ratin			Unit
Mar		RP124xxx3x	1.7 to 5.5	V
VIN	input voltage	RP124xxx4x	2.4 to 5.5	V
Та	Operating Temperature		-40 to 85	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ Refer to POWEWR DISSIPATION for detailed information.

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ELECTRICAL CHARACTERISTICS

 $V_{IN} = V_{SET} + 1.0 \text{ V}, I_{OUT} = 1.5 \text{ mA}, C_{IN} = C_{OUT} = 1.0 \mu\text{F}$, unless otherwise noted. The specifications surrounded by ______ are guaranteed by design engineering at -40°C ≤ Ta ≤ 85°C.

RP124x E	RP124x Electrical Characteristics: LDO Section(Ta = 25°C)								
Symbol	Parameters	Test Con	ditions	Min.	Тур.	Max.	Unit		
				x0.992		x1.008	N		
	Quitout Valtage	V _{SET} > 2.0 V		x0.987		x1.013	V		
VOUT	Oulput voltage			-16		16	m\/		
		$VSET \leq 2.0 V$		-26		26	IIIV		
Іоит	Output Current			100			mA		
	Output Voltage		V _{SET} > 2.0 V	-1		1	%		
Δνουτ	When Switching Mode	$1 \ \mu A \le IOUT \le IOUTH$	$V_{\text{SET}} \leq 2.0 \ \text{V}$	-20		20	mV		
ΔVουτ /ΔΙουτ	Load Regulation	$1.5 \text{ mA} \le I_{OUT} \le 100 \text{ I}$	-40	2	40	mV			
V _{DIF}	Dropout Voltage	I _{OUT} = 100 mA		I _{OUT} = 100 mA		Refe <i>Elec</i>	fer to Product-specifi ectrical Characteristic		ecific istics
laa	Supply Current	Vce = Vin, Iout = 0 mA			0.2	0.42	μA		
155	Supply Current					0.5	μA		
Іоитн	Fast Mode Switching Current	I_{OUT} = From Light Load to Heavy Load, V_{IN} = 5.0 V			0.5		mA		
IOUTL	Low Power Mode Switching Current	I_{OUT} = From Heavy Load to Light Load, V_{IN} = 5.0 V		0.08			mA		
ΔV_{OUT}	Line Regulation	V_{SET} + 0.5 V \leq $V_{IN} \leq$ 5.5 V			0.02	0.2	%/V		
Isc	Short Current Limit	V _{OUT} = 0 V			65		mA		
VCEH	CE Pin Input Voltage, high	RP124xxxxB/D		1.0			V		
V _{CEL}	CE Pin Input Voltage, low	RP124xxxxB/D				0.4	V		
R _{DISN}	Auto-discharge NMOS On-resistance	$V_{IN} = 4.0 \text{ V}, \text{ V}_{CE} = 0 \text{ V}$	/, RP124xxxxD		50		Ω		

All test items listed under Electrical Characteristics are done under the pulse load condition Tj \approx Ta = 25°C.

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ELECTRICAL CHARACTERISTICS (continued)

The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$.

			Vou	г [V]			V	r\/1
Product Name	Ta = 25°C			-40°C ≤ Ta ≤ 85°C			V DIF [V]	
Nume	Min.	Тур.	Max.	Min.	Тур.	Max.	Тур.	Max.
RP124x12xx	1.184	1.200	1.216	1.174	1.200	1.226	0.640	0.975
RP124x15xx	1.484	1.500	1.516	1.474	1.500	1.526	0.410	0.660
RP124x18xx	1.784	1.800	1.816	1.774	1.800	1.826	0.230	0.380
RP124x21xx	2.084	2.100	2.116	2.073	2.100	2.127	0.150	0.285
RP124x22xx	2.183	2.200	2.217	2.172	2.200	2.228		
RP124x23xx	2.282	2.300	2.318	2.271	2.300	2.329	0.130	0.230
RP124x24xx	2.381	2.400	2.419	2.369	2.400	2.431		
RP124x25xx	2.480	2.500	2.520	2.468	2.500	2.532	0.110	0.190
RP124x27xx	2.679	2.700	2.721	2.665	2.700	2.735	0.110	0.100
RP124x28xx	2.778	2.800	2.822	2.764	2.800	2.836		
RP124x30xx	2.976	3.000	3.024	2.961	3.000	3.039	0.100	0.160
RP124x31xx	3.076	3.100	3.124	3.060	3.100	3.140		
RP124x33xx	3.274	3.300	3.326	3.258	3.300	3.342	0.000	0.145
RP124x36xx	3.572	3.600	3.628	3.554	3.600	3.646	0.090	0.143

RP124x Product-specific Electrical Characteristics: LDO Section

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ELECTRICAL CHARACTERISTICS (continued)

 C_{IN} = 1.0 $\mu F,\,C_{\text{BM}}$ = 0.22 $\mu F,$ unless otherwise noted.

The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$.

RP124x Electrical Characteristics: Battery Monitor Section (Ta = 25°C)							
Symbol	Parameters	Test Con	ditions	Min.	Тур.	Max.	Unit
			$1.7 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V},$	V _{IN} /3-20	V _{IN} /3	VIN/3+20	
			RP124xxx3x	V _{IN} /3-25	V _{IN} /3	Vin/3+25	m\/
VBM	Output voltage	- 10 μA ≤ IBM ≤ 10 μA	$2.4 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V},$	V _{IN} /4-20	V _{IN} /4	V _{IN} /4+20	IIIV
			RP124xxx4x	V _{IN} /4-25	V _{IN} /4	Vin/4+25	
law	Output Current	$1.7 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}, \text{ R}$	-10		10		
IBM	Output Current	2.4 V ≤ V _{IN} ≤ 5.5 V, RP124xxx4x		_10		10	μΑ
I _{SSBM}	Supply Current	$V_{\text{IN}} = V_{\text{CE}} = 3.6 \text{ V}$, I_{BN}		0.1	0.2	μA	
Varuati	CE Pin Input	1.7 V ≤ V _{IN} ≤ 5.5 V, R	P124xxx3E	10			V
VCEHBM	Voltage, high	Voltage, high $2.4 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}, \text{RP124xxx4E}$		1.0			v
Manage	CE Pin Input	1.7 V ≤ V _{IN} ≤ 5.5 V, R			64	V	
VCELBM	Voltage, low	2.4 V ≤ V _{IN} ≤ 5.5 V, R			0.4	V	
RdISNBM	Auto-discharge NMOS On- resistance	$V_{\text{IN}} = 4.0 \text{ V}, \text{ V}_{\text{CE}} = 0 \text{ V}$	/, RP124xxxxE		50		Ω

All test items listed under Electrical Characteristics are done under the pulse load condition Tj \approx Ta = 25°C.

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APPLICATION INFORMATION

TYPICAL APPLICATION



RP124xxxxB/D Typical Application Circuit



RP124xxxxE Typical Application Circuit

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Timing Chart Example of RP124xxxxE Circuit

The above diagram shows the example of using the RP124xxxxE typical application circuit and its timing chart. Connecting BM pin and ADC input pin of MCU enables monitoring the battery voltage. Controlling the start-up and stop of Battery Monitor with CE pin by the timing based on the ADC sampling reduces power consumption of the entire system. When monitoring the battery voltage, set the waiting time (tw) in order to stabilize waveform after the CE input voltage is set to "H". It is recommended to set tw \geq 10 ms for this product.

Notes on External Components

- Phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use a 1.0-μF or more output capacitor (C_{OUT}) between the VOUT and GND pins, and a 0.1-μF to 0.22-μF capacitor (C_{BM}) between the BM and GND pins with shortest-distance wiring. In case of using a tantalum type capacitor with a large ESR (Equivalent Series Resistance), the output might become unstable. Evaluate your circuit including consideration of frequency characteristics.
- Connect a 1.0-µF or more input capacitor (C_{IN}) between the VDD and GND pins with shortest-distance wiring.

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TECHNICAL NOTES

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed its rated voltage, rated current or rated power. When designing a peripheral circuit, please be fully aware of the following points.

- The high impedance of the wirings may result in noise pickup and unstable operation of the device. Reduce the impedance of the VDD and GND wirings.
- When an intermediate voltage other than V_{IN} or GND is input to the CE pin, a supply current may be increased with a through current of a logic circuit in the IC. The CE pin is neither pulled up nor pulled down, therefore an operation is not stable at open.

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TYPICAL CHARACTERISTICS

Typical Characteristics are intended to be used as reference data; they are not guaranteed.



RP124x28xx, V_{IN} = 3.8 V, I_{OUT} = 1.5 mA





RP124x36xx, V_{IN} = 4.6 V, I_{OUT} = 1.5 mA



2) LDO Supply Current vs. Temperature (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF) RP124x12xx, V_{IN} = 2.2 V RP124x18xx, V_{IN} = 2.8 V



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3) BM Supply Current vs. Temperature (C_{IN} = Ceramic 1.0 µF, C_{BM} = Ceramic 0.1 µF) RP124xxx3x, V_{IN} = 3.6 V RP124xxx4x, V_{IN} = 3.6 V



4) BM Output Voltage vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F, Ta = 25°C) RP124xxx3x RP124xxx4x



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5) BM Output Voltage vs. Temperature (C_{IN} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F) RP124xxx3x, V_{IN} = 3.6 V RP124xxx4x, V_{IN} = 3.6 V

6) BM Supply Current vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F, Ta = 25°C) RP124xxx3x RP124xxx4x



7) LDO Dropout Voltage vs. Temperature (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F) RP124x12xx RP124x18xx







8) LDO Dropout Voltage vs. Output Current (C_{IN} = Ceramic 1.0 μF, C_{OUT} = Ceramic 1.0 μF) RP124x12xx RP124x18xx











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9) LDO Dropout Voltage vs. Set Output Voltage (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C)

10) LDO Output Voltage vs. Output Current (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xx RP124x18xx

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RP124x28xx





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11) LDO Output Voltage vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx RP124x18xx

12) LDO Supply Current vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx



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13) LDO Supply Current vs. Output Current (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx RP124x18xx

14) Ripple Rejection vs. Frequency (C_{IN} = none, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xx, V_{IN} = 2.2 V RP124x18xx, V_{IN} = 2.8 V



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15) Ripple Rejection vs. Input Voltage (C_{IN} = none, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xx, I_{OUT} = 100 µA RP124x18xx, I_{OUT} = 100 µA







0.1kHz

1kHz





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RP124x28xx, I_{OUT} = 30mA



RP124x18xx, I_{OUT} = 30mA







16) LDO Input Transient Response (C_{IN} = Ceramic 0.1 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx, I_{OUT} = 100 μ A, t_R = t_F = 5 μ s RP124x12xx, I_{OUT} = 30 mA, t_R = t_F = 5 μ s



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RP124x12xx





RP124x18xx V_{IN} = 2.8 V, I_{OUT} = 1 μ A <=> 10 mA, t_R = t_F = 5 μ s





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RP124x18xx





RP124x28xx V_{IN} = 3.8 V, I_{OUT} = 1 μ A <=> 10 mA, t_R = t_F = 5 μ s



RP124x28xx V_{IN} = 3.8 V, I_{OUT} = 10 mA <=> 30 mA, t_R = t_F = 5 µs



RP124x28xx V_{IN} = 3.8 V, I_{OUT} = 1.5 mA <=> 10 mA, t_R = t_F = 5 µs 20



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RP124x36xx



RP124x36xx $V_{IN} = 4.6 \text{ V}, I_{OUT} = 10 \text{ mA} <=> 30 \text{ mA}, t_R = t_F = 5 \text{ }\mu\text{s}$





 V_{IN} = 4.6 V, I_{OUT} = 1.5 mA <=> 10 mA, t_R = t_F = 5 µs

Output Current

Output Voltage

20 15

10

5

0

Output Current[mA]

RP124x36xx

Output Voltage[V]

3.70 3.65

3.60

3.55

3.50



18) LDO Turning-on with CE Pin (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xD, V_{IN} = 2.2 V, V_{CE} = 0 V => 2.2 V RP124x18xD, V_{IN} = 2.8 V, V_{CE} = 0 V => 2.8 V



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4

2

CE Input Voltage[V]

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19) LDO Turning-off with CE Pin (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xD, V_{IN} = 2.2 V, V_{CE} = 2.2 V => 0 V RP124x18xD, V_{IN} = 2.8 V, V_{CE} = 2.8 V => 0 V

Σ

Output Voltage

2

1



RP124x28xD, V_{IN} = 3.8 V, V_{CE} = 0 V => 3.8 V







CE Input Voltage

IOUT = 0mA

IOUT = 30mA

IOUT = 100mA



Output Voltage

RP124x36xD, V_{IN} = 4.6 V, V_{CE} = 0 V => 4.6 V

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RP124x364D, V_{IN} = 4.6 V, V_{CE} = 0 V <=> 4.6 V



20) BM Turning-on/off with CE Pin (C_{IN} = Ceramic 1.0 µF, C_{BM} = Ceramic 0.1 µF, 0.22 µF, Ta = 25°C) RP124xxx3x, V_{IN} = 3.6 V, V_{CE} = 0 V <=> 3.6 V RP124xxx4x, V_{IN} = 3.6 V, V_{CE} = 0 V <=> 3.6 V

Output Voltage[V] 1.5

1.0

0.5

0.0







-2 2 10 12 0 6 8 14 4 Time[ms]

RP124xxx4x, V_{IN} = 5.5 V, V_{CE} = 0 V <=> 5.5 V

Output Voltage

CE Input Voltage

 $CBM = 0.1 \mu F$

CBM = 0.22µF

5

4

3

CE Input Voltage[V]







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21) Inrush Current at CE Pin's Activation (C_{IN} = Ceramic 0.1 μ F, Ta = 25°C) RP124x12xx, V_{IN} = 2.2 V, V_{CE} = 0 V => 2.2 V ① RP124x12xx, V_{IN} = 2.2 V, V_{CE} = 0 V => 2.2 V ②

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22) ESR vs. Output Current (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F) Measuring Frequency : 10 Hz to 2 MHz, Ambient Temperature : -40°C to 5°C LDO BM







RP124xxx3x, V_{IN} = 1.7V to 5.5V









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LDO RP124x36xx, V_{IN} = 3.6 V to 5.5 V

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POWER DISSIPATION

DFN1212-6

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 14 pcs

Measurement Result

(Ta = 25°C, Tjmax = 125°C) Item **Measurement Result Power Dissipation** 850 mW Thermal Resistance (0ja) θja = 117°C/W Thermal Characterization Parameter (ψjt) ψ jt = 50°C/W

θja: Junction-to-Ambient Thermal Resistance

wit: Junction-to-Top Thermal Characterization Parameter





Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

DFN1212-6

Ver. B



DFN1212-6 Package Dimensions

^{*} The tab on the bottom of the package is substrate level (GND). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.



POWER DISSIPATION

SOT-23-5

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

Item	Measurement Conditions		
Environment	Mounting on Board (Wind Velocity = 0 m/s)		
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)		
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm		
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square		
Through-holes	φ 0.3 mm × 7 pcs		

Measurement Result

(Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

θja: Junction-to-Ambient Thermal Resistance

wjt: Junction-to-Top Thermal Characterization Parameter





Measurement Board Pattern

SOT-23-5

Ver. A





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- 8. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 9. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 10. There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact Ricoh sales or our distributor before attempting to use AOI.
- 11. Please contact Ricoh sales representatives should you have any questions or comments concerning the products or the technical information.



Ricoh is committed to reducing the environmental loading materials in electrical devices with a view to contributing to the protection of human health and the environment. Ricoh has been providing RoHS compliant products since April 1, 2006 and Halogen-free products since April 1, 2012.

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